CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT573AFT

1. Functional Description

Octal D-Type Latch with 3-State Outputs

2. General

The 74VHCT573A is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gateC²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high impedance state.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output ^(Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

3. Features

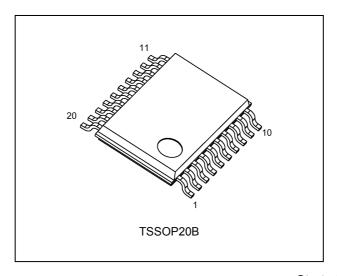
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: Propagation delay time = 7.7 ns (typ.) at $V_{CC} = 5.0$ V
- (4) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25^{\circ}\text{C}$
- (5) Compatible with TTL inputs: $V_{IL} = 0.8 \text{ V (max)}$

$$V_{IH} = 2.0 \text{ V (min)}$$

- (6) Power down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Low noise: $V_{OLP} = 1.5 \text{ V (max)}$
- (9) Pin and function compatible with the 74 series (74ACT/HCT/AHCT etc.) 573 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

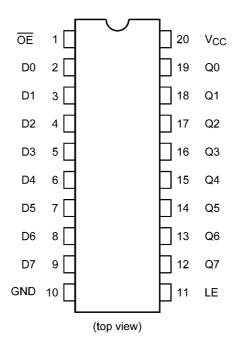
4. Packaging



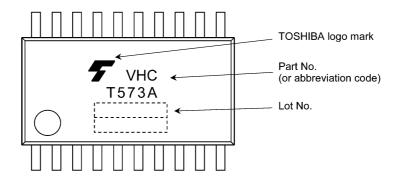
Start of commercial production



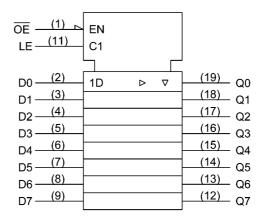
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



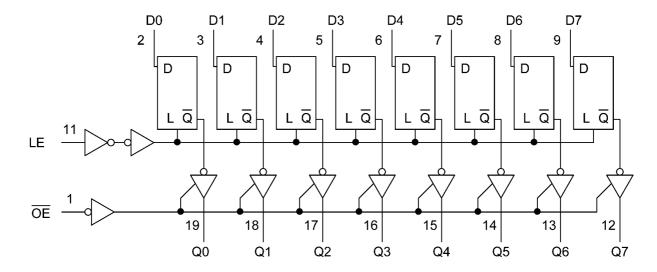
8. Truth Table

INPUT OE	INPUT LE	INPUT D	OUTPUT
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't careZ: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

9. System Diagram





10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-20	mA
Output diode current	l _{ok}	(Note 3)	±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P_{D}	(Note 4)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in off-state

Note 2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

11. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}	(Note1)	0 to 5.5	V
		(Note2)	0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs and bus inputs must be tied to either V_{CC} or GND.

Note1: $V_{CC} = 0 V$ Note2: High or low state



12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V_{IH}	_		4.5 to 5.5	2.0	_		V
Low-level input voltage	V_{IL}	_		4.5 to 5.5	_	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.40	4.50		V
			$I_{OH} = -8mA$	4.5	3.94	_		
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	V
			I _{OL} = 8mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μΑ
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	_	0.5	μА

12.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.40	_	V
			I_{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	40.0	μΑ
	Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	5.0	μА

12.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit	
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.40	_	V
			I_{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μА
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	20.0	μА



12.4. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}\text{C}$, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	V _{CC} (V)	Тур.	Limit	Unit
Minimum pulse width (LE)	t _{w(H)}	5.0 ± 0.5	_	6.5	ns
Minimum setup time	t _S	5.0 ± 0.5	_	1.5	ns
Minimum hold time	t _h	5.0 ± 0.5	_	3.5	ns

12.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85°C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (LE)	t _{w(H)}	5.0 ± 0.5	8.5	ns
Minimum setup time	t _S	5.0 ± 0.5	1.5	ns
Minimum hold time	t _h	5.0 ± 0.5	3.5	ns

12.6. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (LE)	$t_{w(H)}$	5.0 ± 0.5	8.5	ns
Minimum setup time	t _S	5.0 ± 0.5	2.0	ns
Minimum hold time	t _h	5.0 ± 0.5	3.5	ns

12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	_	7.7	12.3	ns
(LE-Q)					50	_	8.5	13.3	
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	_	5.1	8.5	ns
(D-Q)					50	_	5.9	9.5	
3-state output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	5.0 ± 0.5	15	_	6.3	10.9	ns
					50	_	7.1	11.9	
3-state output disable time	t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	_	8.8	11.2	ns
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	5.0 ± 0.5	50	_		1.0	ns
Input capacitance	C _{IN}		_			_	4	10	pF
Output capacitance	C _{OUT}		_			_	9	_	
Power dissipation capacitance	C _{PD}	(Note 2)	_			_	25	_	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs of latch operate can be gained by the following equation.

 C_{PD} (total) = 14 + 11 × n



12.8. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	13.5	ns
(LE-Q)					50	1.0	14.5	
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	9.5	ns
(D-Q)					50	1.0	10.5	
3-state output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	5.0 ± 0.5	15	1.0	12.5	ns
					50	1.0	13.5	
3-state output disable time	t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	1.0	12.0	ns
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	5.0 ± 0.5	50	-	1.0	ns
Input capacitance	C _{IN}		_	·	·		10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

12.9. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	15.5	ns
(LE-Q)					50	1.0	17.0	
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	11.0	ns
(D-Q)					50	1.0	12.0	
3-state output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	5.0 ± 0.5	15	1.0	14.0	ns
					50	1.0	15.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	1.0	14.0	ns
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	5.0 ± 0.5	50	_	1.0	ns
Input capacitance	C _{IN}		_				10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

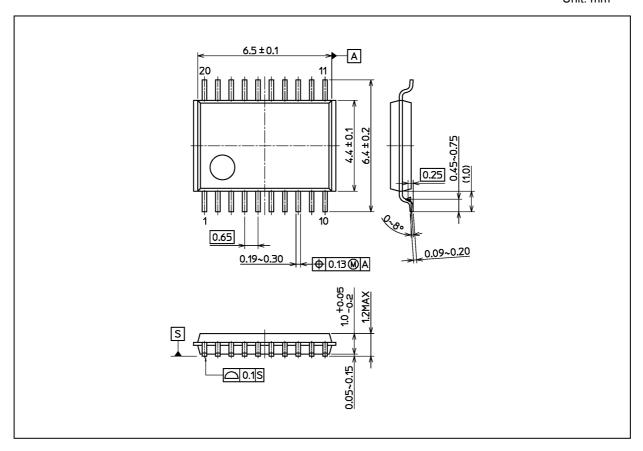
12.10. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	1.1	1.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-1.1	-1.5	
Minimum high-level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0		2.0	
Maximum low-level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0		0.8	



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

Rev.3.0



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